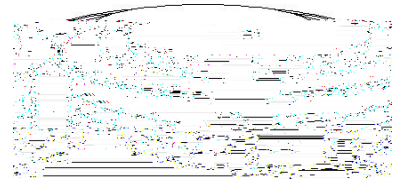


ZP3200-RECTIFIER DIODE

Jiangsu Yangjie Runau Semiconductor



Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
Operating temperature	T_j	-40	+125		°C	
Storage temperature	T_{stg}	-40	+125		°C	
Thermal resistance - junction to case	R_{jc}		0.0057		°C/W	Double sided cooled
Thermal resistance - case to heatsink	R_{cs}		0.0015		°C/W	Double sided cooled
Mounting force	P			70	kN	

Weight

W

1.85

kg.